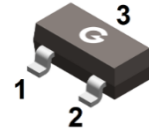
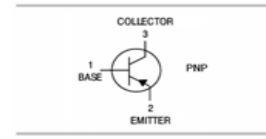


Features

- Excellent h_{FE} Linearity
- Complementary to TS9014
- RoHS compliant with Halogen-free
- Qualified to AEC-Q101 Standards

HF



SOT-23

Mechanical Data

- Case: SOT-23
- Molding Compound: UL Flammability Classification Rating 94V-0
- Terminals: Matte tin-plated leads; solderability-per MIL-STD-202, Method 208

Ordering Information

Part Number	Package	Shipping Quantity	Marking Code
TS9015-L	SOT-23	3000 pcs / Tape & Reel	M6
TS9015-H	SOT-23	3000 pcs / Tape & Reel	M6

Maximum Ratings (@ $T_A = 25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Value	Unit
Collector-Base Breakdown Voltage	V_{CBO}	-50	V
Collector-Emitter Breakdown Voltage	V_{CEO}	-45	V
Emitter-Base Breakdown Voltage	V_{EBO}	-5	V
Continuous Collector Current	I_C	-100	mA
Peak Collector Current	I_{CM}	-200	mA

Thermal Characteristics

Parameter	Symbol	Value	Unit
Power Dissipation($T_A = 25^\circ\text{C}$)	P_D	200	mW
Thermal Resistance Junction-to-Air ^{*1}	$R_{\theta JA}$	420	$^\circ\text{C/W}$
Thermal Resistance Junction-to-Case ^{*1}	$R_{\theta JC}$	250	$^\circ\text{C/W}$
Thermal Resistance Junction-to-Lead ^{*1}	$R_{\theta JL}$	180	$^\circ\text{C/W}$
Junction Temperature Range	T_J	-55 ~ +150	$^\circ\text{C}$
Storage Temperature Range	T_{STG}	-55 ~ +150	$^\circ\text{C}$

Note 1: The data tested by surface mounted on a minimum recommended FR-4 board

Electrical Characteristics (@ $T_A = 25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C = -100\mu\text{A}, I_E = 0$	-50	-	-	V
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = -0.1\text{mA}, I_B = 0$	-45	-	-	V
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E = -100\mu\text{A}, I_C = 0$	-5	-	-	V
Collector Cut-off Current	I_{CBO}	$V_{CB} = -50\text{V}, I_E = 0$	-	-	-0.1	μA
Emitter Cut-off Current	I_{EBO}	$V_{EB} = -5\text{V}, I_C = 0$	-	-	-0.1	μA
DC Current Gain	h_{FE}	$V_{CE} = -5\text{V}, I_C = -1\text{mA}$	200	-	1000	-
Collector-emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = -100\text{mA}, I_B = -10\text{mA}$	-	-	-0.3	V
Base-emitter Saturation Voltage	$V_{BE(sat)}$	$I_C = -100\text{mA}, I_B = -10\text{mA}$	-	-	-1	V
Transition Frequency	f_T	$I_C = -10\text{mA}, V_{CE} = -5\text{V}$ $f = 30\text{MHz}$	100	-	-	MHz

Classification of h_{FE}

Rank	L	H
Range	200-450	450-1000

Ratings and Characteristic Curves (@ $T_A = 25^\circ\text{C}$ unless otherwise specified)

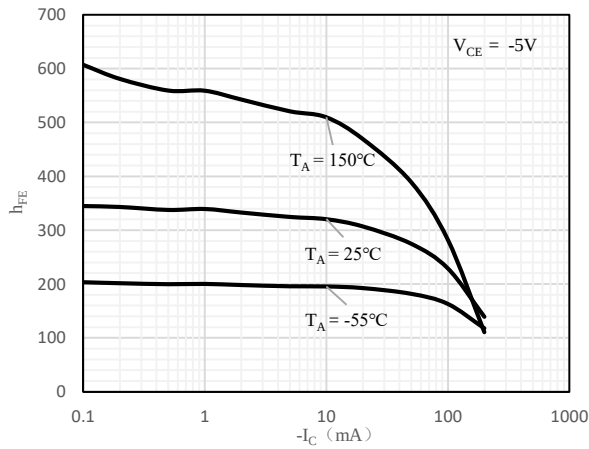


Fig 1 h_{FE} vs. I_C

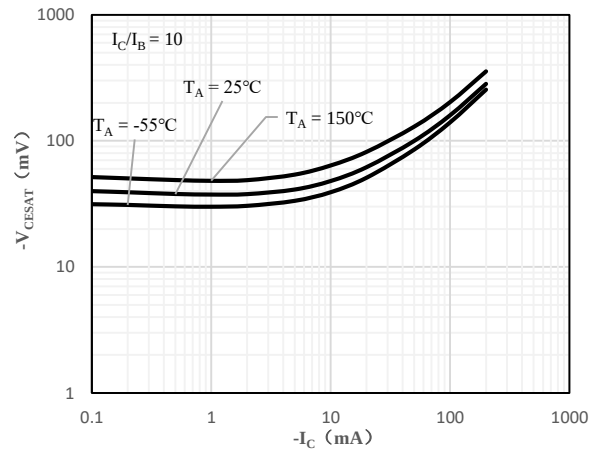


Fig 2 $V_{CE(sat)}$ vs. I_C

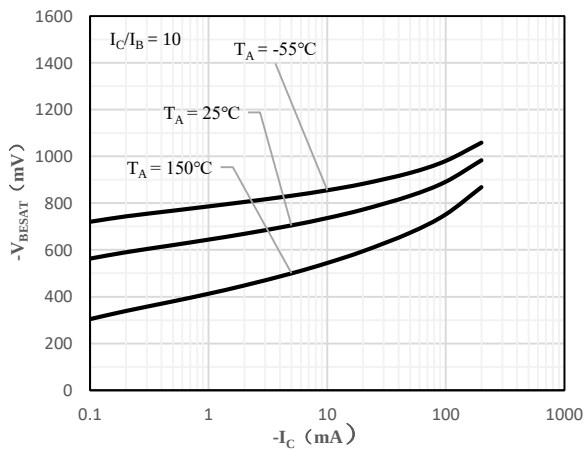


Fig 3 $V_{BE(sat)}$ vs. I_C

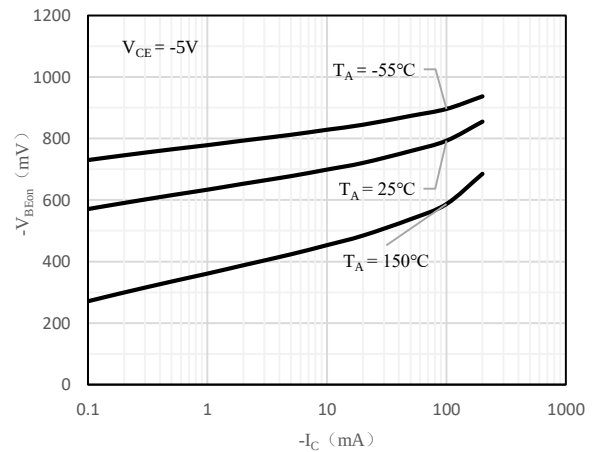


Fig 4 $V_{BE(on)}$ vs. I_C

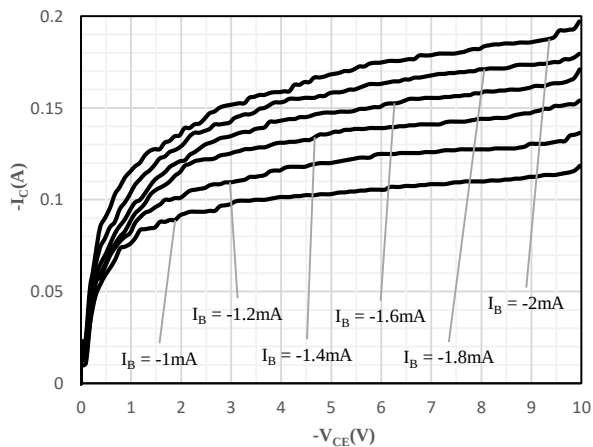


Fig 5 I_C vs. V_{CE}

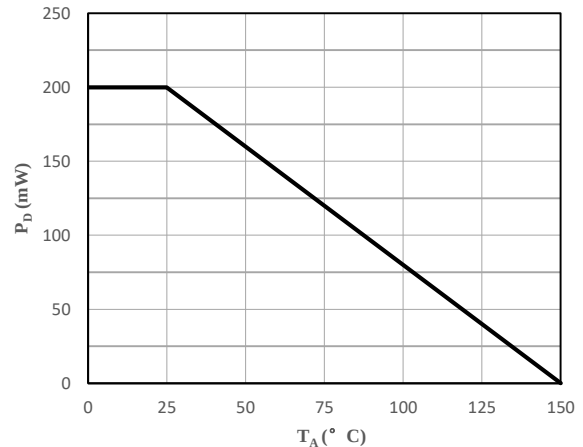


Fig 6 P_D vs. T_A

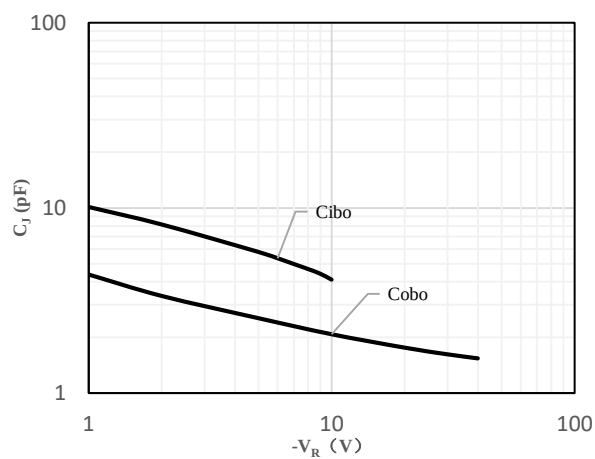
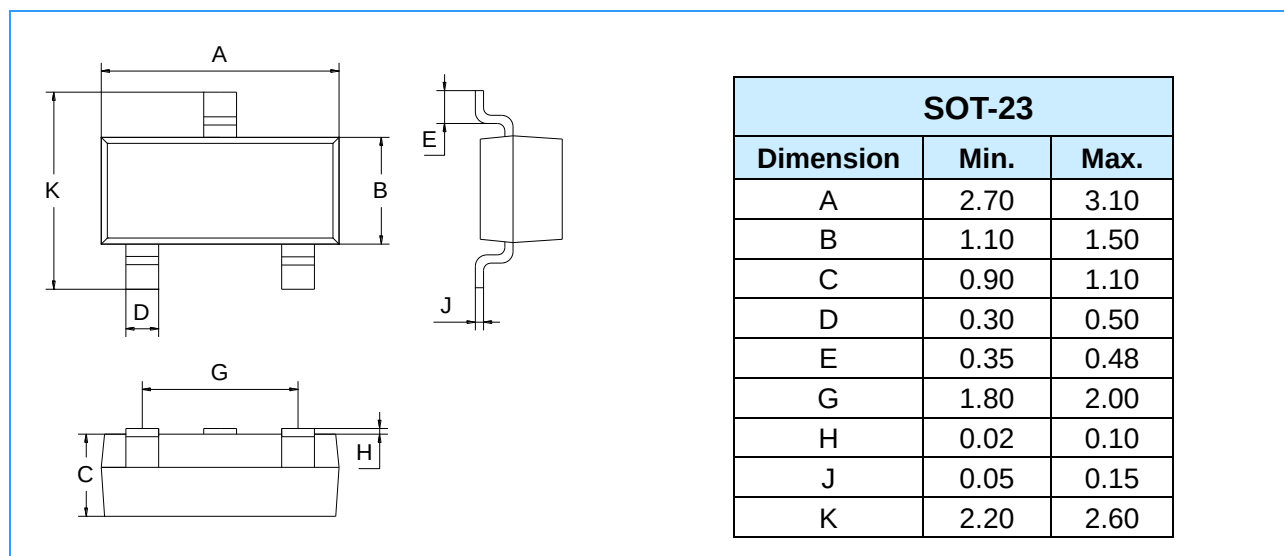


Fig 7 C_j vs. V_R

Package Outline Dimensions (Unit: mm)



Package Outline Dimensions (Unit: mm)

